## NSN 5962-01-019-9962

Memory Microcircuit - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5962-01-019-9962
Body Length:
Between 0.755 inches and 0.790 inches
Body Width:
Between 0.265 inches and 0.300 inches
Body Height:
Between 0.155 inches and 0.175 inches
Maximum Power Dissipation Rating:
650.0 milliwatts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
Features Provided:
Hermetically sealed and monolithic and positive outputs and bipolar and w/buffered output and programmable and programmed and
w/enable and w/open collector and w/storage and w/decoded output
Inclosure Material:
Ceramic and glass
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Transistor-transistor logic
Input Circuit Pattern:
10 input
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
5.5 volts power source
Time Rating Per Chacteristic:
30.00 nanoseconds propagation delay time, low to high level output and 30.00 nanoseconds propagation delay time, high to low level
output
Memory Device Type:
Rom
Memory Capacity:
Unknown
Test Data Document:
08783-37654912 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing,
etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)
Terminal Type And Quantity:
16 printed circuit
Shelf Life:

Demilitarization: Voc. domil/mli

**Unit Of Measure:** 

N/a

## NSN 5962-01-019-9962

Memory Microcircuit - Page 2 of 2



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